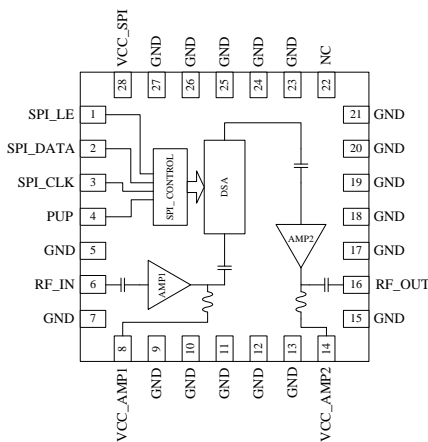


RFDA2046

Digital Controlled Variable Gain Amplifier
1800MHz to 2800MHz

The RFDA2046 is a digital controlled variable gain amplifier featuring high linearity over the entire gain control range with noise figure less than 5.2dB in its maximum gain state. The gain of the 6-bit digital step attenuator is programmed with a serial mode control interface (SPI). The RFDA2046 is packaged in a small 6.0mm x 6.0mm leadless laminate MCM, which contains plated through thermals vias for ultra-low thermal resistance. This module is easy to use with no external matching components required.



Functional Block Diagram

Ordering Information

RFDA2046SQ	Sample bag with 25 pieces
RFDA2046SR	7" Reel with 100 pieces
RFDA2046TR7	7" Reel with 500 pieces
RFDA2046TR13	13" Reel with 2500 pieces
RFDA2046PCK-410	1800MHz to 2800MHz PCBA with 5-piece sample bag



Package: MCM, 28-Pin,
6.0mm x 6.0mm

Features

- Frequency Range 1800MHz to 2800MHz
- Full Internal Matching and No External Bias Inductors
- 6-Bit Digital Step Attenuator
- SPI Serial Control Programming
- Max gain = 41dB at 2.6GHz
- Gain Control Range = 31.5dB (0.5dB Step Size)
- High OIP3/P1dB = +41dBm/ 28dBm
- Single +5V Supply
- Small 28-Pin, 6.0mm x 6.0mm, MCM
- Power-up Programming

Applications

- Cellular, 3G, LTE Infrastructure
- WiBro, WiMax, LTE
- Microwave Radio
- High-linearity Power Control

Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage	+5.5	V _{DC}
DC Supply Current	760	mA
Power Dissipation	3200	mW
Max RF Input Power for Long Term Operation (50Ω)	-5	dBm
Max RF Input Power for Short Term Operation (50Ω)	+20	dBm
Operating Temperature (T _{CASE})	-40 to +85	°C
Storage Temperature	-40 to +150	°C
Junction Temperature	+165*	°C
ESD Rating (HBM)	1000 (Class 1C)	V
Moisture Sensitivity Level	MSL3	

*MTTF = 1.0E6 hours at 165°C junction temperature



Caution! ESD sensitive device.



RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2011/65/EU

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

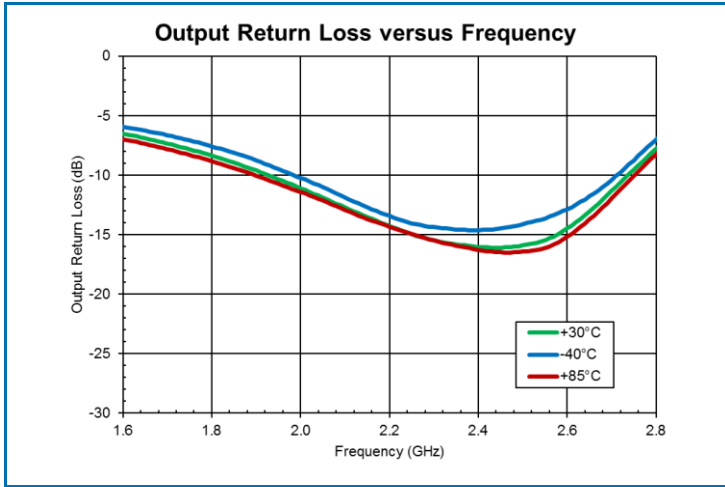
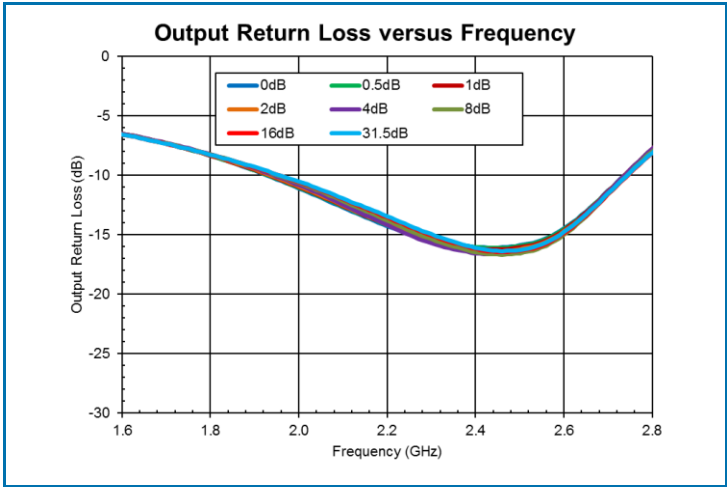
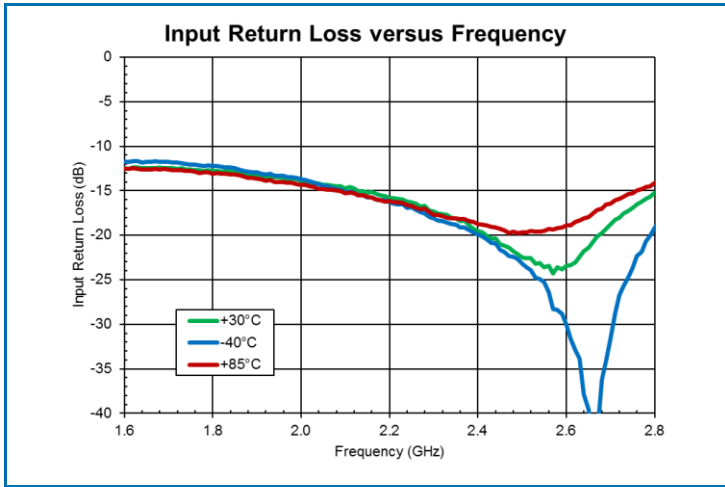
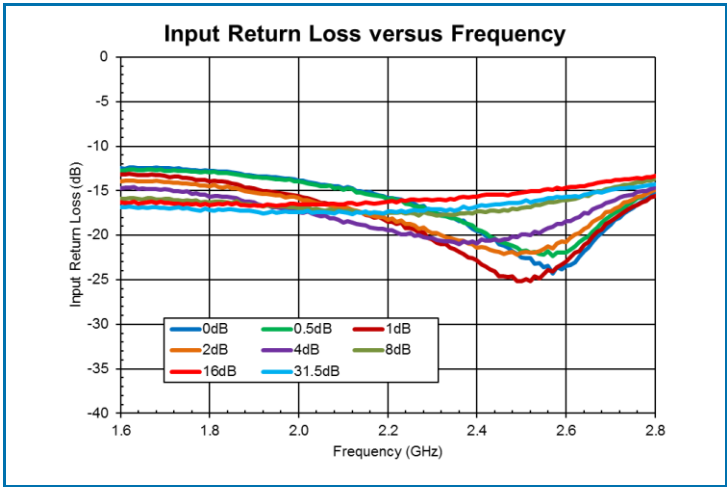
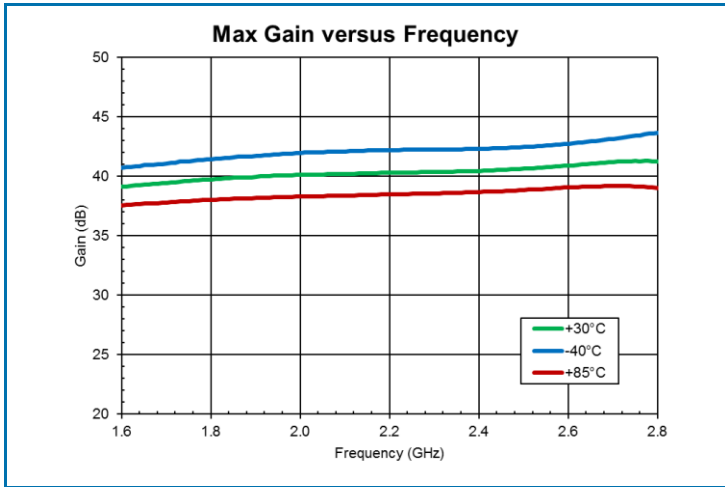
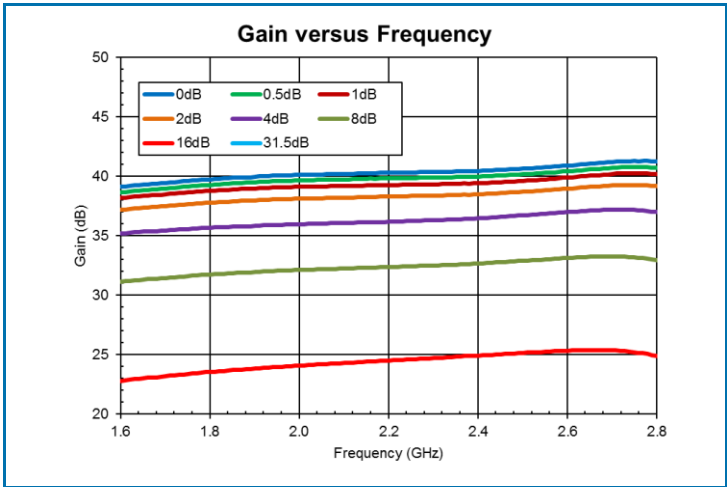
Parameter	Specification			Unit	Condition
	Min	Typ	Max		
Overall					T = 25°C, V_{CC} = V_{DD} = 5V, standard application circuit, measured at 2600MHz
Frequency Range	1800		2800	MHz	
Max Gain		41		dB	Attenuation = 0dB
Gain Control Range		31.5		dB	
Step Accuracy	+/- (0.1+5% attenuation setting)			dB	Major state error up to 2800MHz
P1dB		28		dBm	Attenuation = 0dB
Output IP3		41		dBm	P _{OUT} = 19dBm/tone, 1MHz spacing
Control Interface		6		Bit	SPI interface
Settling Time		250		ns	t _{ON} , t _{OFF} (10%/90% RF)
Noise Figure		5.2		dB	Attenuation = 0dB
Impedance		50		Ω	
Input Return Loss		15		dB	
Output Return Loss		12		dB	
Total Supply Voltage	4.75	5	5.25	V	
Supply Current		360		mA	From V _{CC_SPI} , V _{CC_AMP1} and V _{CC_AMP2}
Thermal Resistance		17.7		°C/W	Junction to backside of device

Typical RF Performance at Key Operating Frequencies

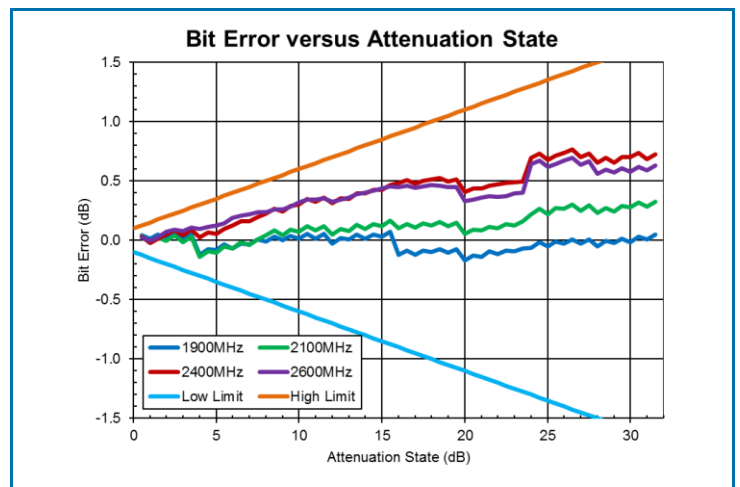
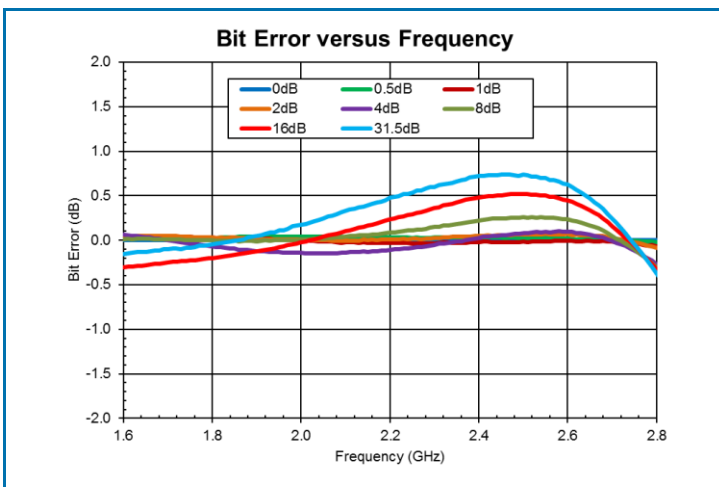
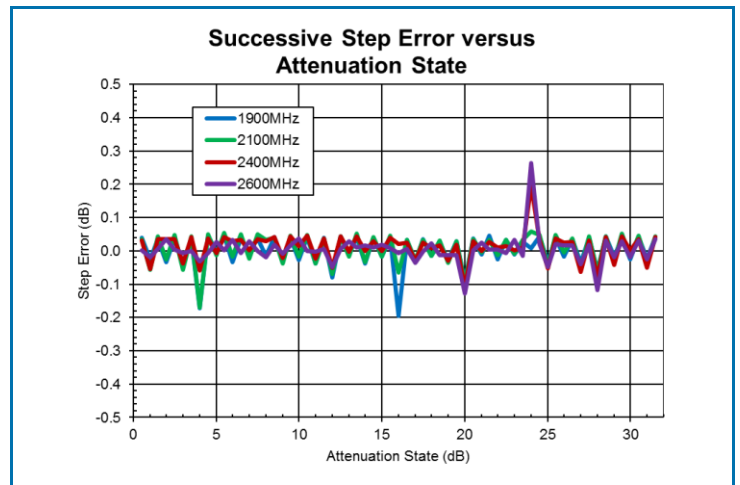
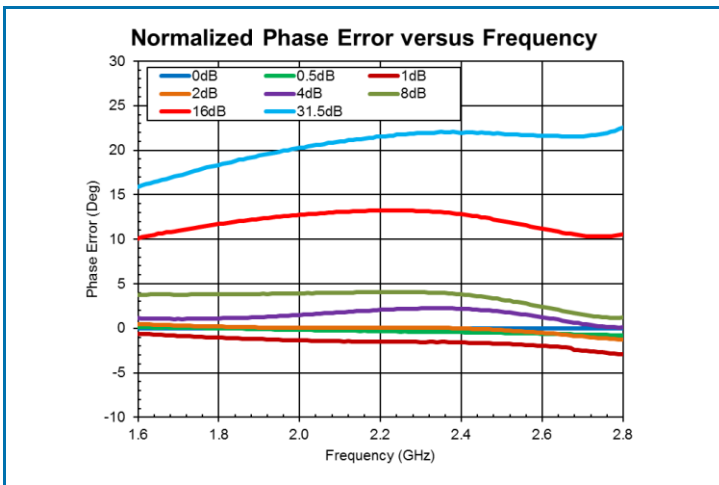
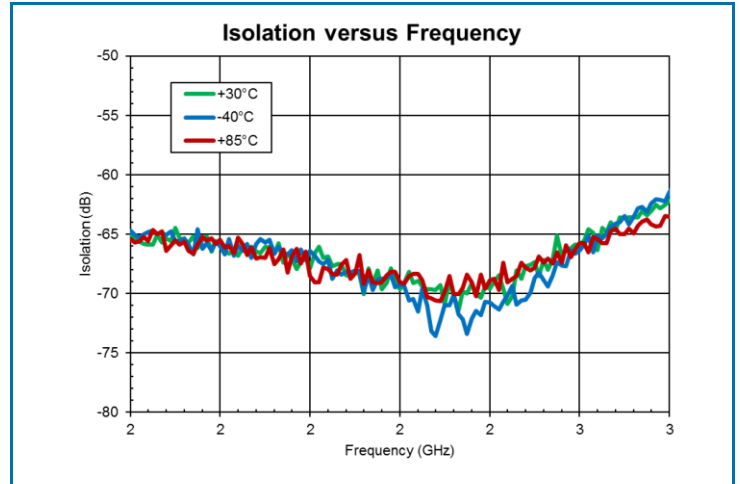
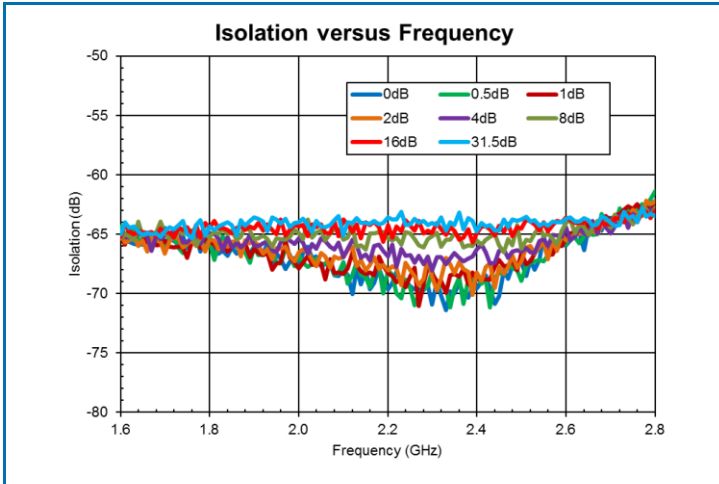
Parameter	Unit	1800MHz	2000MHz	2400MHz	2500MHz	2600MHz	2700MHz	2800MHz
Max Small Signal Gain	dB	39.5	40	40	40	41	41	41
Output P1dB	dBm	27.4	28	28	28	28	28	27.5
Output IP3 (1)	dBm	38	38	40	41	41	40	39
Input Return Loss	dB	13	14	15	15	15	15	15
Output Return Loss	dB	8.2	11	14	14	12	11	8
Noise Figure	dB	5.1	5.2	5.2	5.2	5.2	5.2	5.2

Note: (1) Output IP3 is tested at $P_{OUT} = 19\text{dBm/ tone}$ and 1MHz spacing

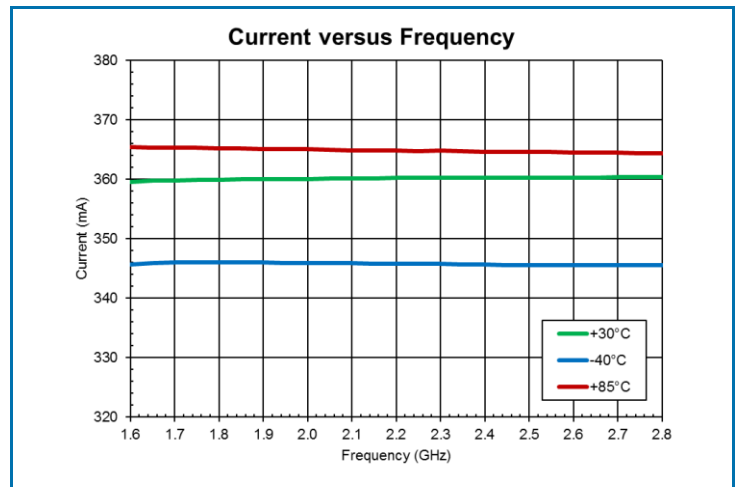
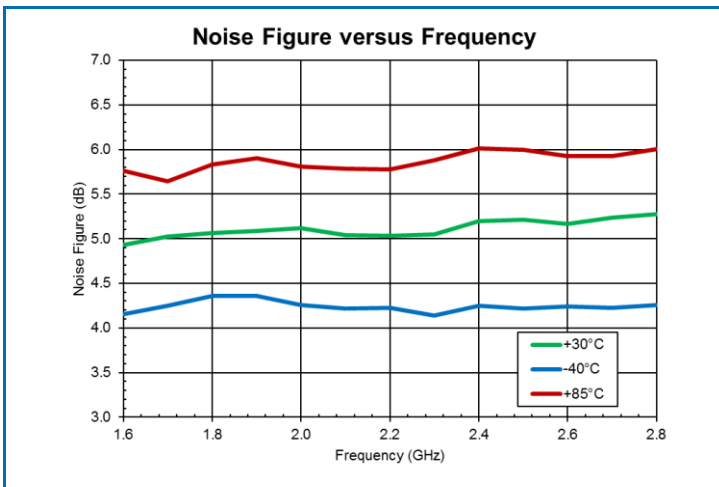
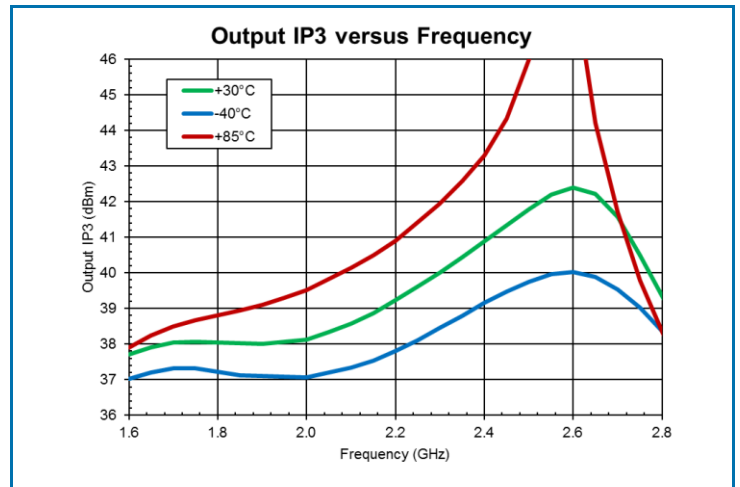
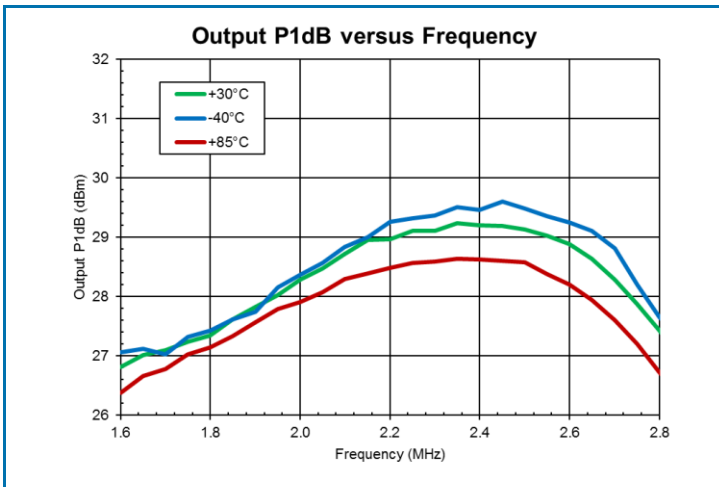
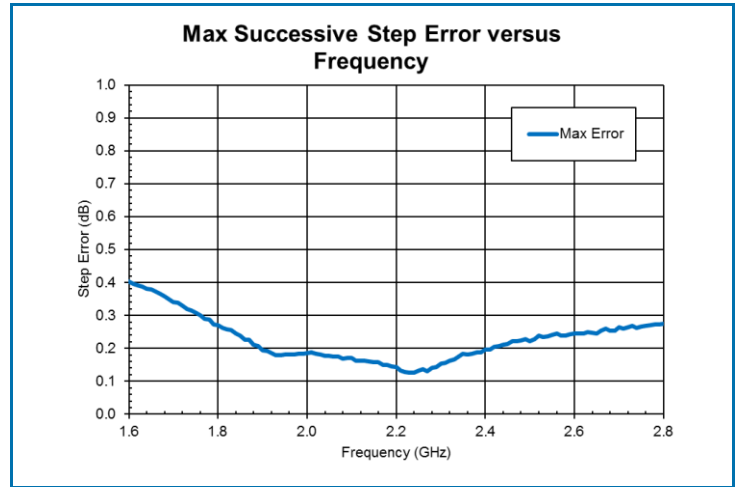
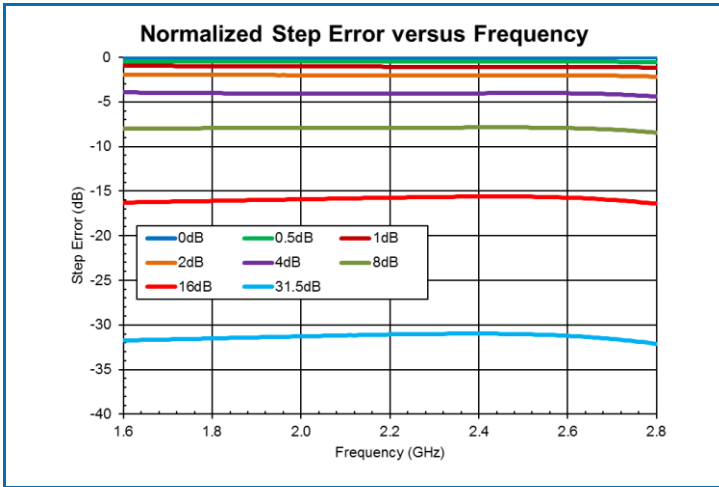
Typical Performance:



Typical Performance:



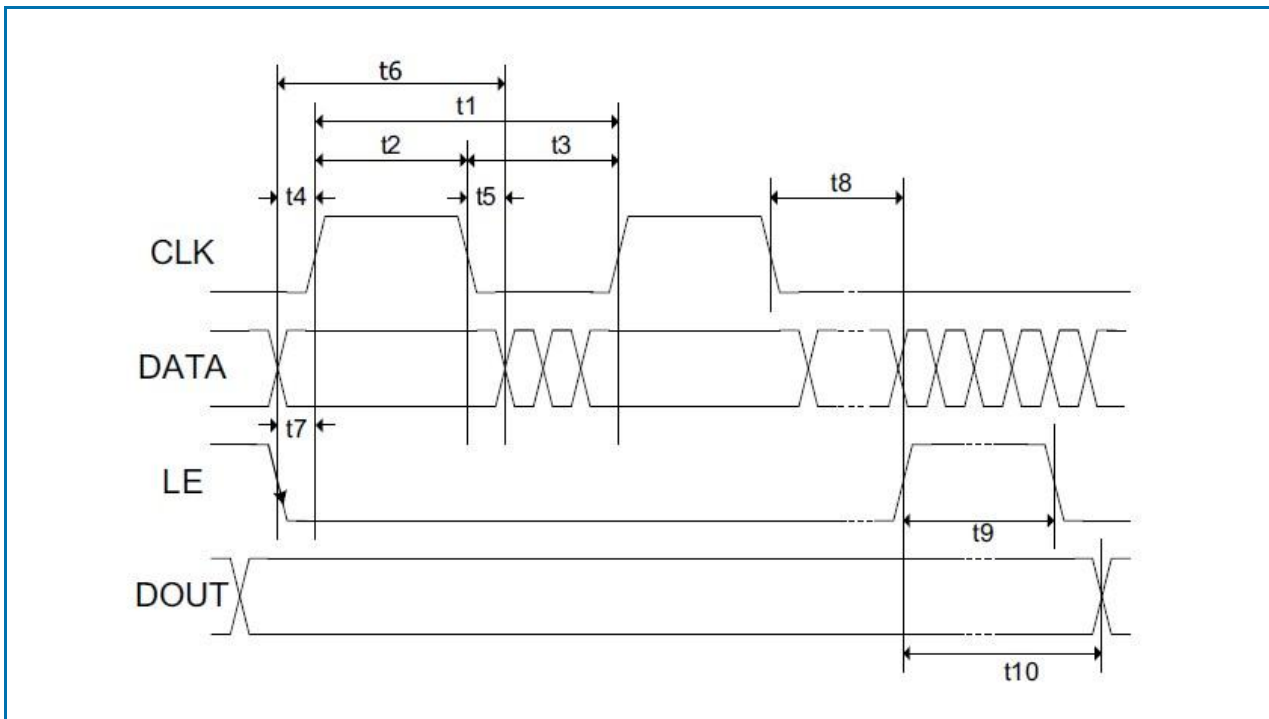
Typical Performance:



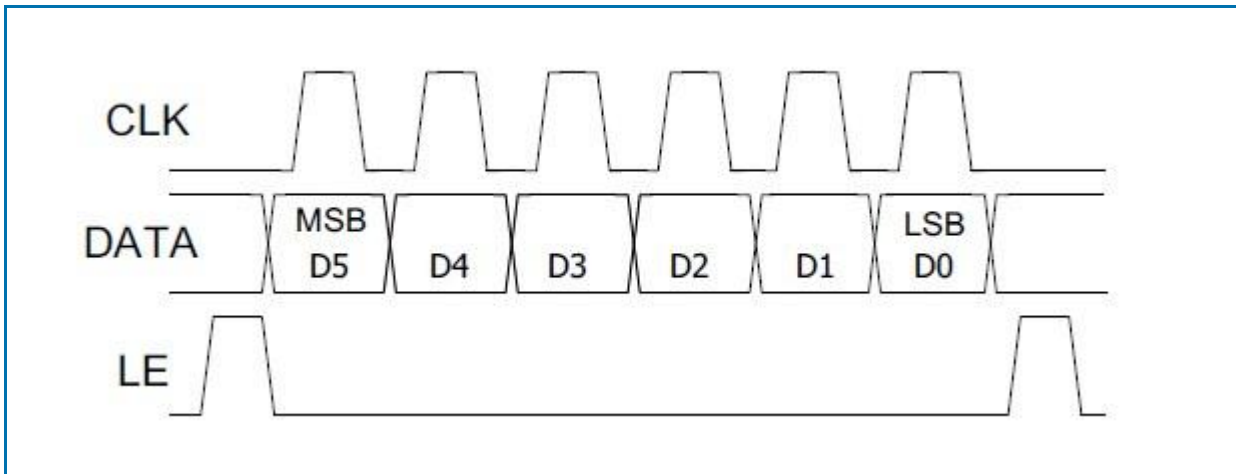
Truth Table

Control Bit						Gain Relative to Maximum Gain
D5	D4	D3	D2	D1	D0	
1	1	1	1	1	1	0dB
1	1	1	1	1	0	-0.5dB
1	1	1	1	0	1	-1dB
1	1	1	0	1	1	-2dB
1	1	0	1	1	1	-4dB
1	0	1	1	1	1	-8dB
0	1	1	1	1	1	-16dB
0	0	0	0	0	0	-31.5dB

SPI Timing Diagram



Programming Example: 6-Bit



SPI Timing Diagram Specifications

Parameter	Limit	Unit	Comment
t1	25	MHz max	CLK Frequency
t2	20	ns min	CLK High
t3	20	ns min	CLK Low
t4	5	ns min	DATA to CLK Setup Time
t5	5	ns min	DATA to CLK Hold Time
t6	30	ns min	DATA Valid
t7	5	ns min	LE to CLK Setup Time
t8	5	ns min	CLK to LE Setup Time
t9	10	ns min	LE Pulse Width
t10	20	ns min	Output Set

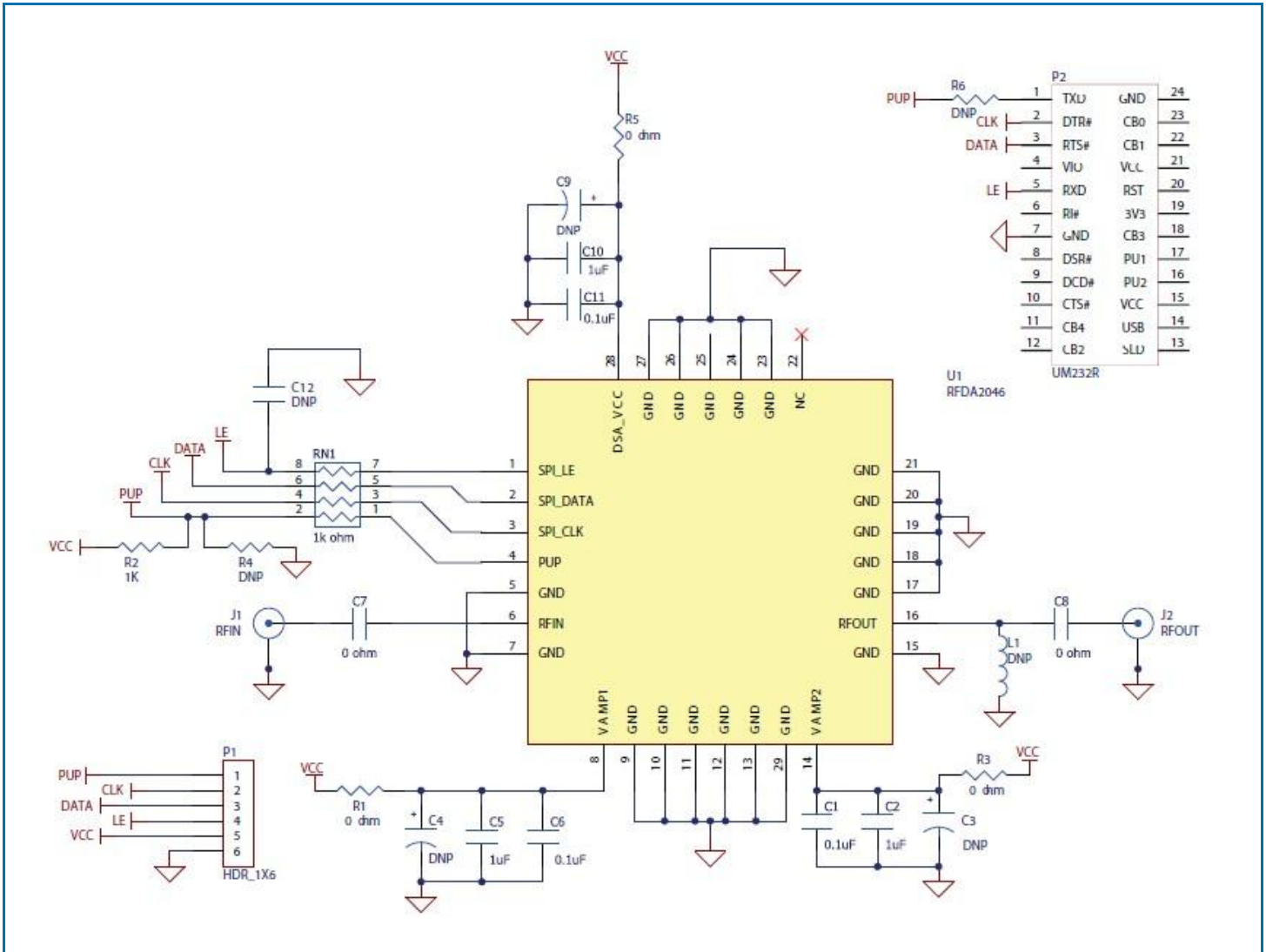
Power-up Programming Truth Table

PUP	Attenuator Setting
Low	Attenuation at max, 31.5dB
High	Attenuation at min, 0dB

Logic Voltage Levels

State	Logic
Low	0V to 0.8V
High	2.0V to 5.0V

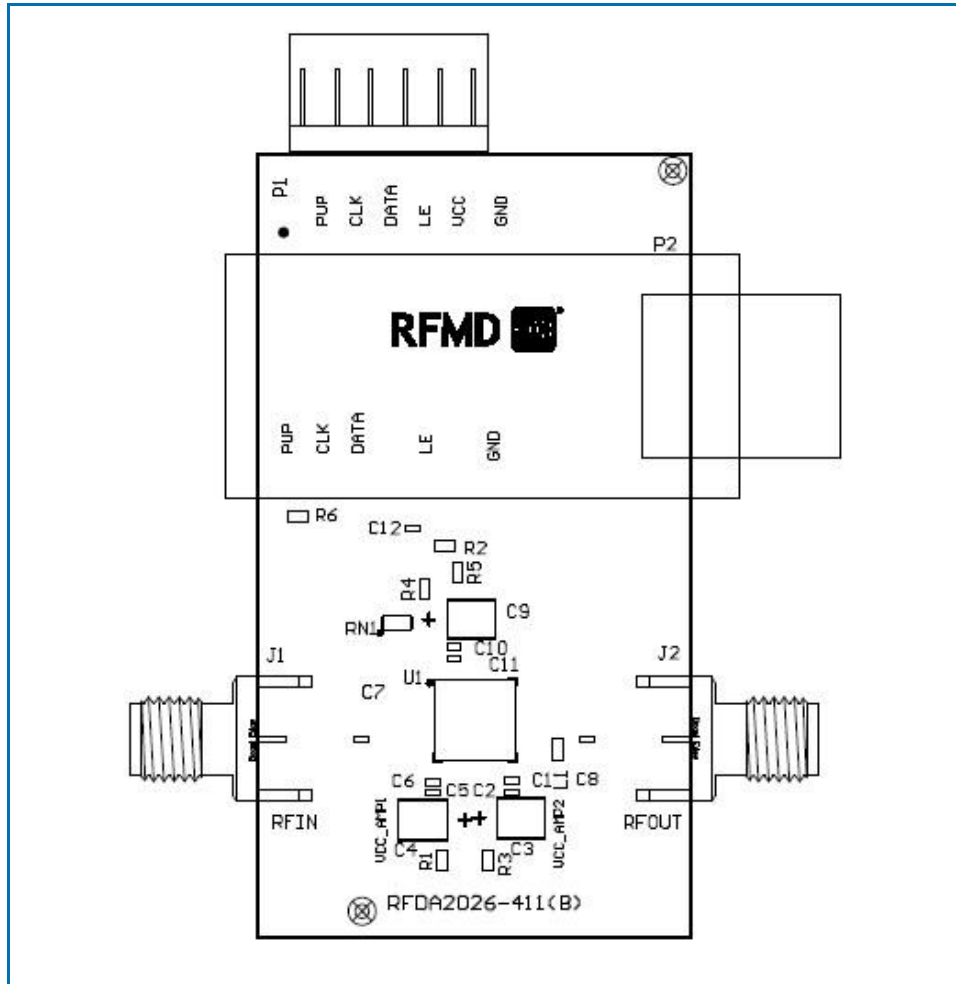
Evaluation Board Schematic



Evaluation Board Bill of Materials (BOM)

Description	Reference Designator	Manufacturer	Manufacturer's P/N
RFDA2046, 6 x 6sq. mm, 28-PIN, LAMINATE	U1	RFMD	RFMD2046
RFDA2026-411(B)		Viasystems	RFDA2026-411(B)
CONN, SMA, END LNCH, FLT, 0.062"	J1-J2	Emerson Network Power	142-0701-821
CONN, HDR, ST, PLRZD, 6-PIN, 0.100"	P1	AMP	640454-6
CONN, SKT, 24-PIN DIP, 0.600", T/H	P2	Aries Electronics Inc.	24-6518-10
CAP, 0.1 μ F, 10%, 16V, X7R, 0402	C1, C6, C11	Murata Electronics	GRM1555R71C104KA88D
CAP, 1 μ F, 10%, 10V, X5R, 0402	C2, C5, C10	Murata Electronics	GRM155R61A105KE15D
RES, 0 Ω , 0402	C7-C8	Kamaya, Inc.	RMC1/16SJPTH
RES, 1K, 5%, 1/16W, 0603	R2	Panasonic Industrial Co.	ERJ-3GEYJ102
RES ARRAY, 4-ELEM, 1K, 5%, SMD 4 x 00402	RN1	KOA Speer Electronics, Inc.	CN1E4KTTD102J
RES, 0 Ω , 0603	R1, R3, R5	KOA Speer Electronics, Inc.	RK73Z1JLTD
DNP	C3-C4, C9, C12	N/A	N/A
DNP	R4, R6	N/A	N/A
DNP	L1	N/A	N/A

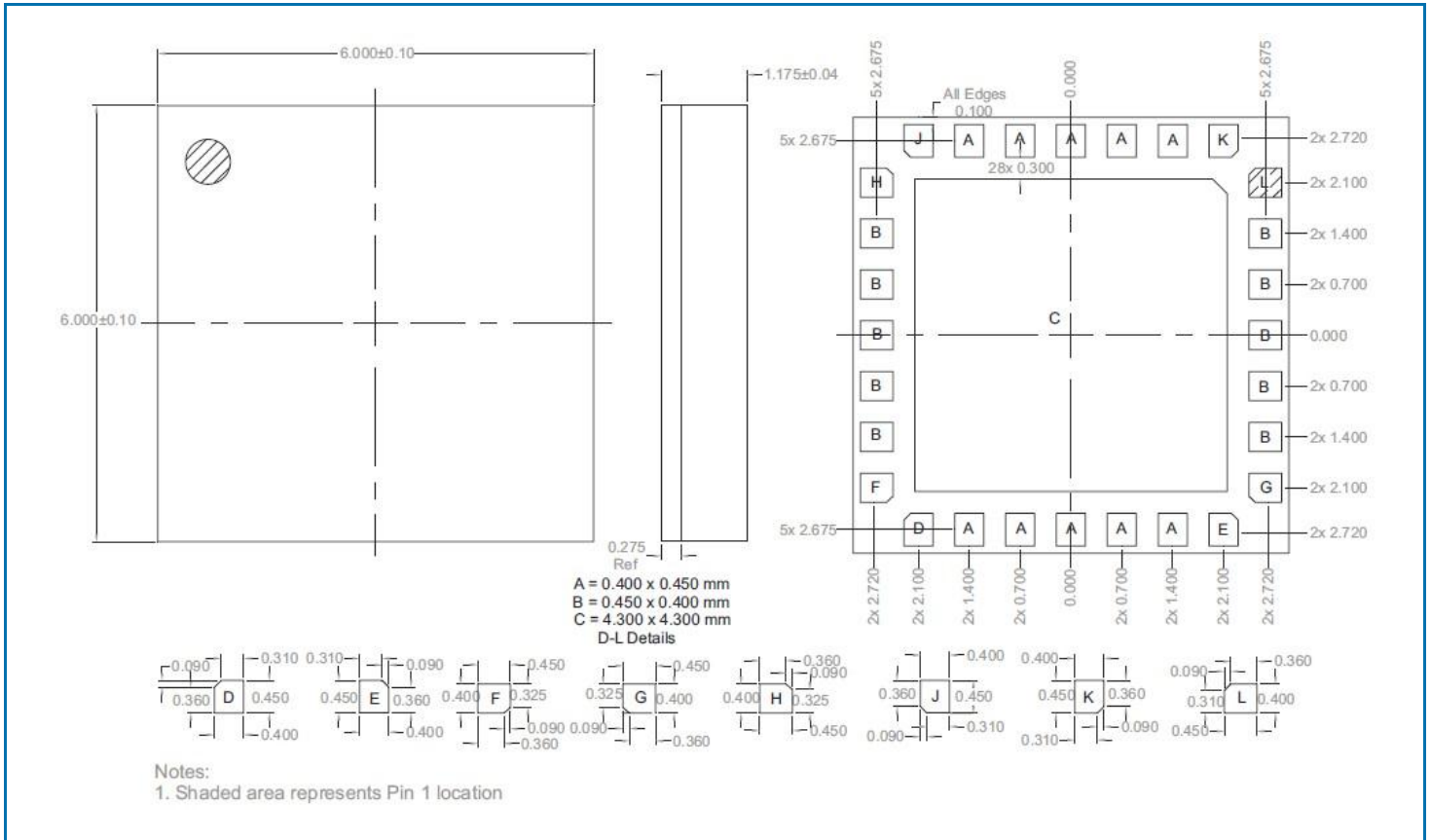
Evaluation Board Assembly Drawing



Pin Names and Descriptions

Pin	Name	Description
1	SPI_LE	Serial latch enable input
2	SPI_DATA	Serial data input
3	SPI_CLK	Serial clock input
4	PUP	Power-up programming pin
5	GND	RF/DC ground connection
6	RF_IN	RF input, with built-in DC block capacitor
7	GND	RF/DC ground connection
8	VCC_AMP1	Supply voltage for amplifier 1
9	GND	RF/DC ground connection
10	GND	RF/DC ground connection
11	GND	RF/DC ground connection
12	GND	RF/DC ground connection
13	GND	RF/DC ground connection
14	VCC_AMP2	Supply voltage for amplifier 2
15	GND	RF/DC ground connection
16	RF_OUT	RF output, with built-in DC block capacitor
17	GND	RF/DC ground connection
18	GND	RF/DC ground connection
19	GND	RF/DC ground connection
20	GND	RF/DC ground connection
21	GND	RF/DC ground connection
22	NC	Do not connect, leave open circuit
23	GND	RF/DC ground connection
24	GND	RF/DC ground connection
25	GND	RF/DC ground connection
26	GND	RF/DC ground connection
27	GND	RF/DC ground connection
28	VCC_SPI	Supply voltage for SPI and DSA chip

Package Outline Drawing (Dimensions in millimeters)



Branding Diagram

